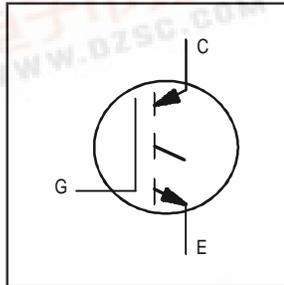


International
IR Rectifier

PD-91766

IRG4CH20KB

IRG4CH20KB IGBT Die in Wafer Form



1200 V
Size 2
Ultra Fast Speed
Short Circuit Rated
6" Wafer

Electrical Characteristics (Wafer Form)

Parameter	Description	Guaranteed (Min/Max)	Test Conditions
$V_{CE(on)}$	Collector-to-Emitter Saturation Voltage	4.5V Max.	$I_C = 5.5A, T_J = 25^\circ C, V_{GE} = 15V$
$V_{(BR)CES}$	Collector-to-Emitter Breakdown Voltage	1200V Min.	$T_J = 25^\circ C, I_{CES} = 250\mu A, V_{GE} = 0V$
$V_{GE(th)}$	Gate Threshold Voltage	3.0V Min., 6.0V Max.	$V_{GE} = V_{CE}, T_J = 25^\circ C, I_C = 250\mu A$
I_{CES}	Zero Gate Voltage Collector Current	300 μA Max.	$T_J = 25^\circ C, V_{CE} = 1200V$
I_{GES}	Gate-to-Emitter Leakage Current	$\pm 11 \mu A$ Max.	$T_J = 25^\circ C, V_{GE} = +/- 20V$

Mechanical Data

Normal Backmetal Composition, Thickness:	Cr-Ni / V-Ag (1kA-2kA-.2.5kA)
Normal Front Metal Composition, Thickness:	99% Al, 1% Si (4 microns)
Dimensions:	0.112" x 0.150"
Wafer Diameter:	150mm, with std. < 100 > flat
Wafer thickness:	.015" + / - .003"
Relevant Die Mechanical Dwg. Number	01-5266
Minimum Street Width	100 Microns
Reject Ink Dot Size	0.25mm Diameter Minimum
Ink Dot Location	Consistent throughout same wafer lot
Recommended Storage Environment:	Store in original container, in dessicated nitrogen, with no contamination
Recommended Die Attach Conditions	For optimum electrical results, die attach temperature should not exceed 300C

Reference Standard IR packaged part (for design) : IRG4PH20K (When available)

Die Outline

NOTES:

- ALL DIMENSIONS ARE SHOWN IN MILLIMETERS (INCHES).
- CONTROLLING DIMENSION: (INCH).
- LETTER DESIGNATION:
S = SOURCE SK = SOURCE KELVIN
G = GATE IS = CURRENTSENSE
- DIMENSIONAL TOLERANCES:
BONDING PADS:
 WIDTH < (.0250) TOLERANCE = +/- (.0005)
 & > 0.635 TOLERANCE = +/- 0.025
 LENGTH > (.0250) TOLERANCE = +/- (.0010)
 OVERALL DIE:
 WIDTH < 1.270 TOLERANCE = +/- 0.102
 & < (.050) TOLERANCE = +/- (.004)
 & > 1.270 TOLERANCE = +/- 0.203
 LENGTH > (.050) TOLERANCE = +/- (.008)
- UNLESS OTHERWISE NOTED ALL DIE ARE GEN III

